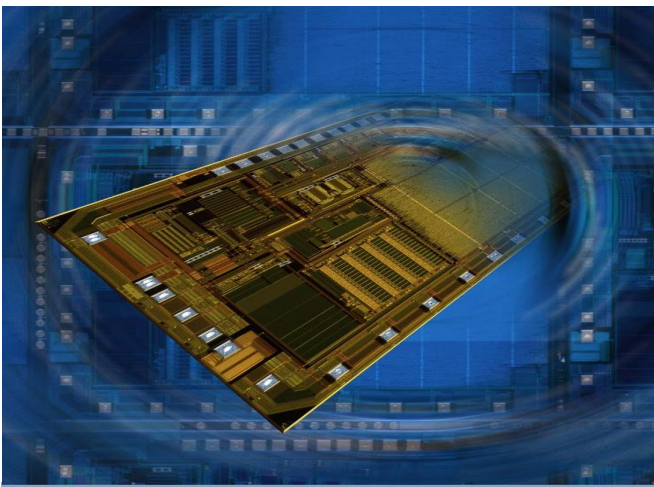


Product Information Ignition Driver with Diagnosis – CK200

**BOSCH**

Invented for life



Ignition Driver with Diagnosis

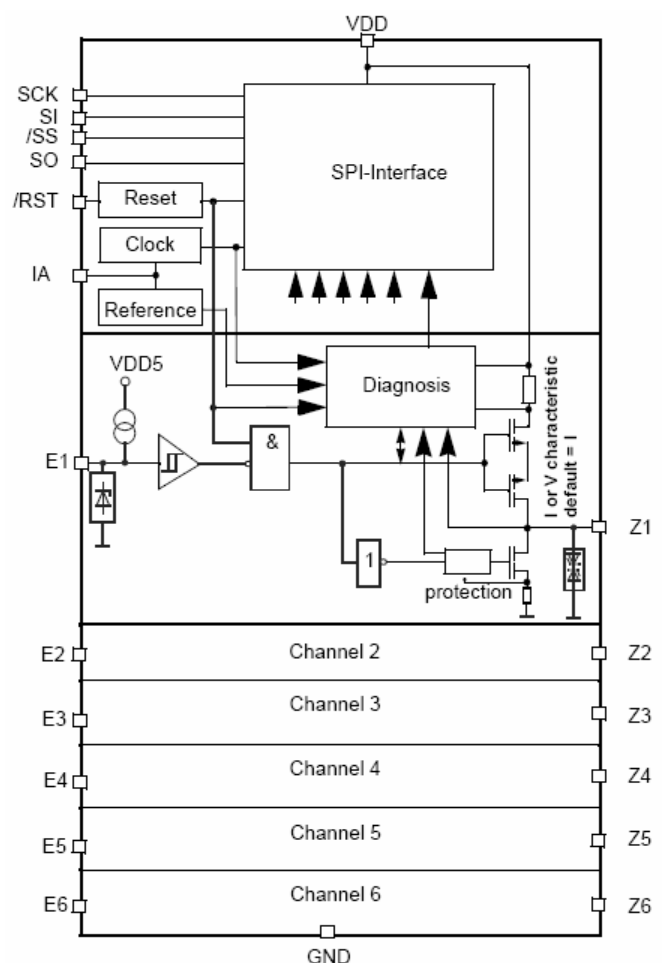
Customer benefits:

- ▶ Excellent system know-how
- ▶ Smart concepts for system safety
- ▶ Secured supply
- ▶ Long- term availability of manufacturing processes and products
- ▶ QS9000 and ISO/TS16949 certified

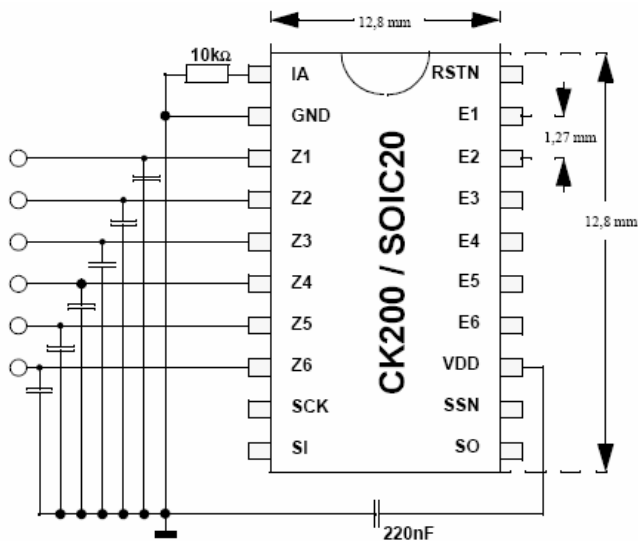
Features

- ▶ 6 channel with programmable
 - operating mode and
 - low side switch (on/off)
- ▶ Bi-Directional-Interface (BDI):
 - OUT: voltage source
 - IN: programmable current monitor I_{TH}
- ▶ Outputs short circuit protected to GND and V_{Batt}
- ▶ Diagnosis:
 - Wiring: short circuit to GND ,short circuit to V_{BATT} or Open load
 - Ignition coil: assessment of current relating to time (t_{COMP}) and level (I_{TH})
- ▶ Serial-Peripheral-Interface (SPI)
- ▶ Single supply VDD (5V)
- ▶ ESD-protection

Block- / functional diagram



Application circuit



Pin description SOIC20

Pin	Description
VDD	Power supply input (5V)
GND	Ground
IA	$R_{\text{extern}} = 10\text{k}\Omega$; reference for current threshold I_{TH} in V-mode, output current in I-mode and oscillator frequency.
E1... 6	Input
Z1... 6	Output
SCK	Input SPI-clock (from μC)
SI	Input serial data (SPI, from μC)
SO	Output serial data (SPI, to μC)
/SS	Slave select (SPI, from μC)
/RST	Input Reset

The application circuit of the CK200 consists of the following parts :

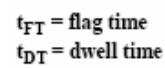
- ▶ Capacitor between [VDD5] and [GND] to stabilize the supply voltage VCC
- ▶ Resistor between [IA] and [GND] reference for current threshold, output current and internal clock
- ▶ Capacitor between [Ziext] and [GND]

Maximum ratings

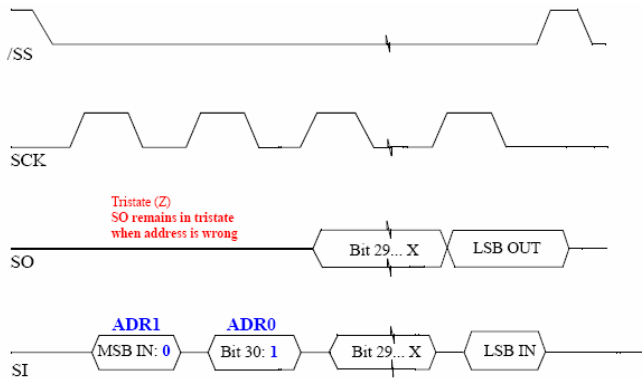
Parameter	Condition / Pins	Symbol	Min.	Max.	Unit
Electrical					
Supply voltage VDD		V_{VDD}	-0.3	5.5	V
Maximum voltage	Pins Ei, i = 1 to 6, IA, /RST, /SS, SCK, SI, SO	V_{X}	-0.3	$V_{\text{VDD}} + 0.3$	V
	Zi, i = 1 to 6	V_{X}	-2	16	V
ESD (Human Body)	R=1.5kΩ, C=100pF Pins Zi, i = 1 to 6	V	-4	4	kV
	R=1.5kΩ, C=100pF all other pins	V	-2	2	kV
Thermal					
Temperature	junction	T_{J}	-40	150	°C
	storage	T_{ST}	-55	150	°C
	ambient for SOIC	T_{A}	-40	125	°C
Thermal resistance		R_{thJC}	60	80	K/W
Operating range					
For operational function		V_{VDD}	4.5	5.5	V
For parameters		V_{VDD}	4.85	5.15	V
Supply current	all low side switch active	I_{VDD}		tbd	mA
Undervoltage switch off	/RST=high, low side switch= active	V_{VDD}	3.0	4.5	V
	/RST=high, low side switch= active or tristate	V_{VDD}		3.0	V
Logic inputs E1 ... E6; SI; /SS; SCK; /RST					
Input low voltage		V_{IL}	-0.3	0.8	V
Input high voltage		V_{IH}	2	$V_{\text{VDD}} + 0.3$	V
Input pull-up currents source	$-0.3 \leq V_{\text{in}} \leq V_{\text{VDD}} - 0.9\text{V}$	I_{in}	-10	-50	uA
SPI frequency (it is recommended to use 2 MHz)					
Frequency SCK		f_{SCK}	0.5	4	MHz

Electrical characteristics

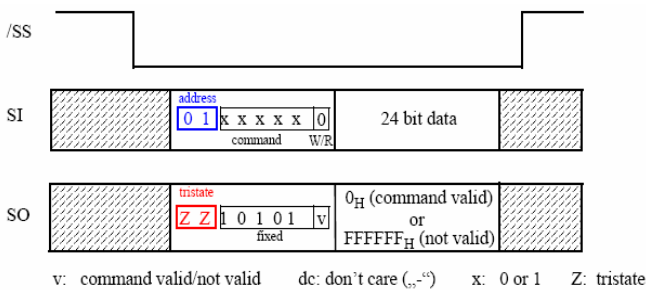
Parameter	Conditions / Comments	Symbol	Min.	Max.	Unit
Logic outputs SO					
Output low voltage	I _{SO} = 2mA	U _{SOL}		0.4	V
Output high voltage	I _{SO} = -2mA	U _{SOH}	V _{VDD} - 0.75		V
leakage current	In tristate; 0V ≤ V _{SO} ≤ V _{VDD}	I _{SO}	-10	10	uA
Oscillator					
Internal frequency	R _{IA} =10kΩ ± 1%	f _{clk}	3.2	4.8	MHz
Internal operating clock period	R _{IA} =10kΩ ± 1% ; T _{clk} = 32 / f _{clk}	T _{clk}	6.66	10.0	μs
High side; Ei = low (default = I - Mode; PR14 = 1)					
Output current	R _{IA} =10kΩ ± 1% I _{ZI} = I _{th} defined by PR13 -PR8 BIT in INIT_Reg min: 010000; max: 101111 not allowed: 11xxxx	-I _{ZI}	8	25	mA
Output voltage	V _{VDD} = 4,85V; I _{ZI} = -25mA	V _{ZI}	4.2		V
Short circuit threshold	SCG	V _{ZI}	0.3	1.0	V
Short circuit switch off delay time	entry in error register	t _{off} /T _{CLK}	11	13	
Short circuit to supply detection voltage	SCB	V _{ZI}	V _{VDD} + 0.1	V _{VDD} + 2.0	V
Open load	-25mA < I _{ZI} < -8mA; k _{OL} = I _{ZI} / I _{ZIOL}	k _{OL}	5	27	
High side; Ei = low (V - Mode; PR14 = 0);					
Output voltage	V _{VDD} = 4.85V; I _{out} = -25mA	V _{ZI}	4.2		V
Output current	R _{IA} = 10kΩ	-I _{ZI}	17.6	100	mA
Short circuit to GND threshold current	-25mA < I _{th} < -8mA and I _{ZISCGmax} = 100mA; k _{SCG} = I _{ZISCG} / I _{th}	k _{SCG}	2.2	12.5	
Short circuit switch off delay time	entry in error register	t _{off} /T _{CLK}	11	13	
Short circuit to supply detection voltage	SCB	V _{ZI}	V _{VDD} + 0.1	V _{VDD} + 2.0	V
Open load	-25mA < I _{ZI} < -8mA; k _{OL} = I _{ZI} / I _{ZIOL}	k _{OL}	5	27	
Low side; Ei = high					
Output voltage	I _{ZI} = 10mA , V _{VDD} ≥ 4.85V	V _{ZI}		0.65	V
Output pull down current	/RST = high	I _{ZI}	30	70	mA
Inverse current	-2.0V ≤ V _{ZI} ≤ 0V	-I _{ZI}	0	40	uA
Short circuit to supply threshold voltage		V _{ZI}	1.25	2.8	V
Short circuit to supply switch off delay time	entry in error register	t _{off} /T _{CLK}	11	13	
Output delay time	C _{ZI} =10nF			10	us
Output rise / fall time	C _{ZI} =10nF			10	us
SPI					
Cycle time	referred to master	t _{cyc}	250		ns
Enable lead time	referred to master		50		ns
Enable lag time	referred to master		125		ns
Data valid	referred to CK200; C _{Load} = 100pF High --> Low: SCK = 0.7V _{VDD} --> SO = 0.1V _{VDD} Low --> High: SCK = 0.7V _{VDD} --> SO = 0.9V _{VDD}			100	ns
Data setup time	referred to master		50		ns
Data hold time	referred to master		20		ns
Disable time	referred to CK200			50	ns
Transfer delay referred to master	command after write		800		ns
	Clock cycles between 2 RD_DIAG		4		
Select time	referred to master		50		ns
Access time	referred to master 2 + 32*1 +3+8		8,225		μs

4

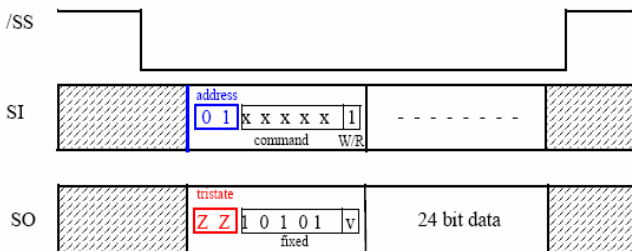
Timing



Write access



Read access



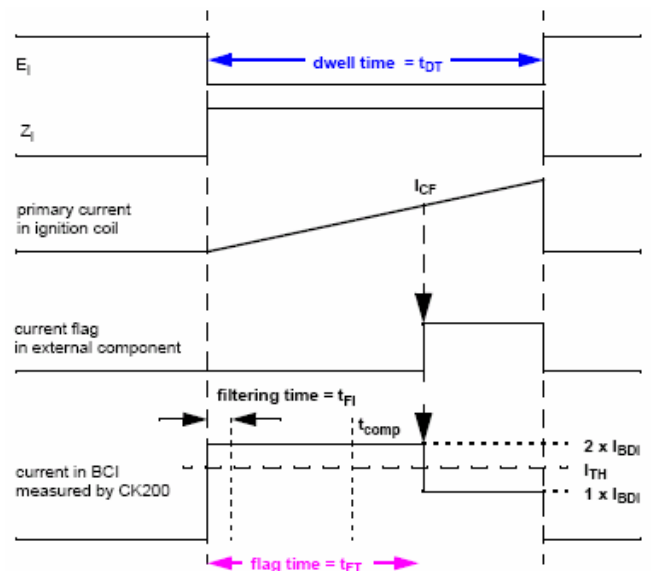
Diagnosis

Wiring diagnosis

DB1	DB0	Description a.)
1	1	Channel ok; Reset value after RD_DIAG
1	0	Short circuit to battery (SCB)
0	0	Open load (OL)
0	0	Short circuit to ground (SCG)

a.) Last failure is stored until reset (/RST or SRST) or end of RD_DIAG

Ignition coil diagnosis (schematic)



The threshold I_{TH} for current assessment of BDI and time value for TCOMP can be modified via SPI.

DB1	DB0	Description
1	1	$t_{FT} \geq t_{COMP} > t_{FI}$
1	0	$0 \leq t_{FT} < t_{COMP}$
0	0	$t_{FT} \geq t_{DT}$
0	0	Any rising edge during $t_{FI} \leq t \leq t_{DT}$

Contact

Robert Bosch GmbH
Sales Semiconductors
Postbox 13 42
72703 Reutlingen
Germany
Tel.: +49 7121 35-2979
Fax: +49 7121 35-2170

Robert Bosch Corporation
Component Sales
38000 Hills Tech Drive
Farmington Hills, MI 48331
USA
Tel.: +1 248 876-7441
Fax: +1 248 848-2818

Robert Bosch K.K.
Component Sales
9-1, Ushikubo 3-chome
Tsuzuki-ku, Yokohama 224
Japan
Tel.: +81 45 9 12-83 01
Fax: +81 45 9 12-95 73

E-Mail: bosch.semiconductors@de.bosch.com

Internet: www.bosch-semiconductors.de

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